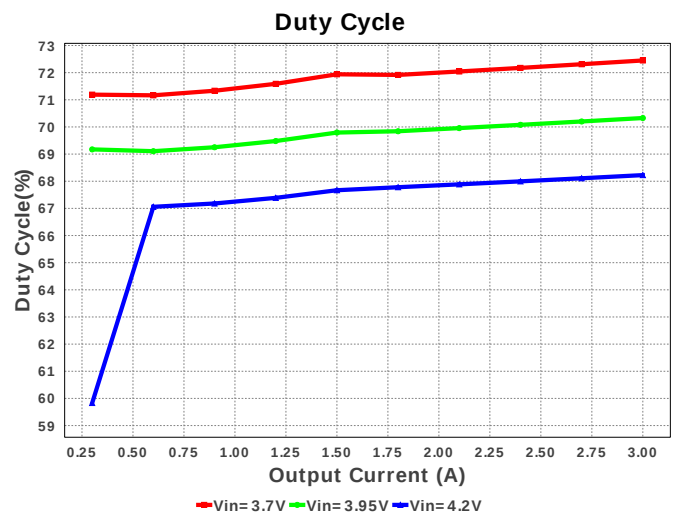
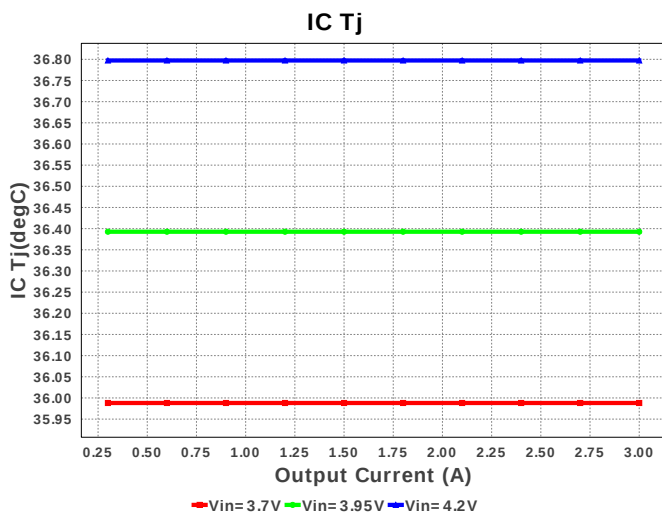
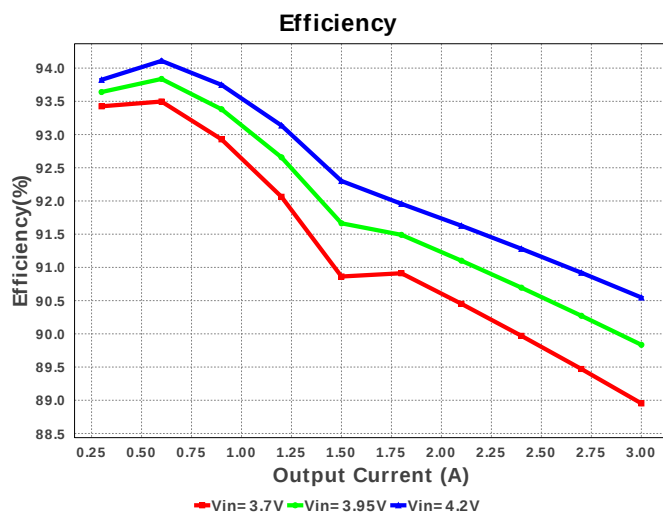
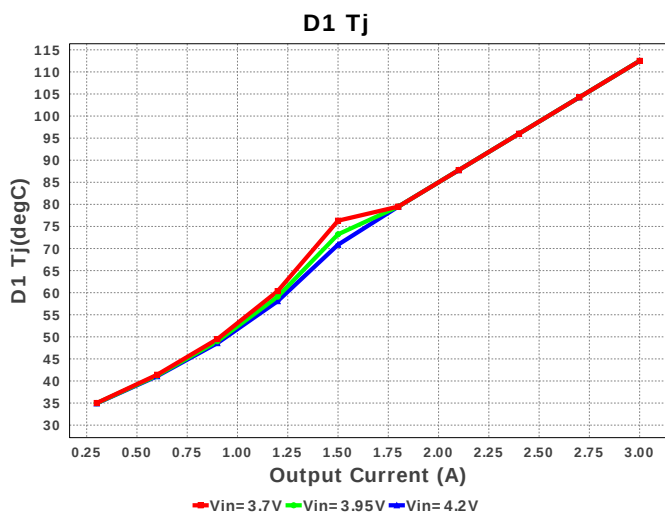
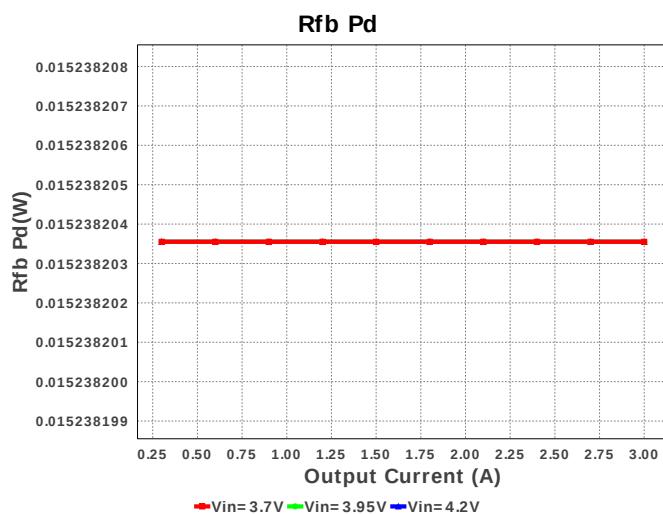
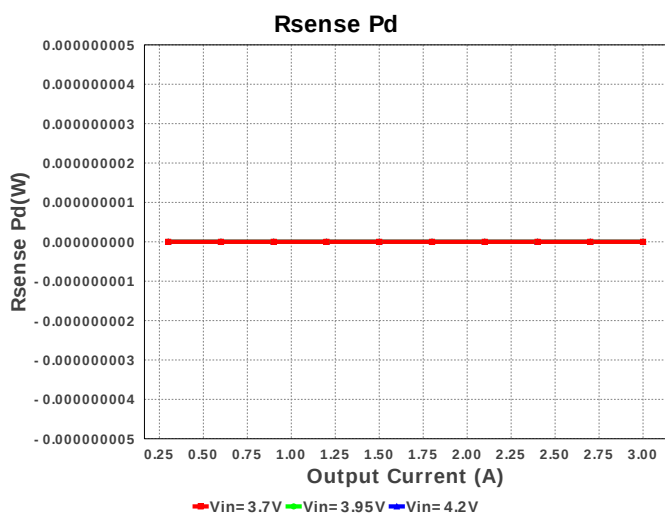
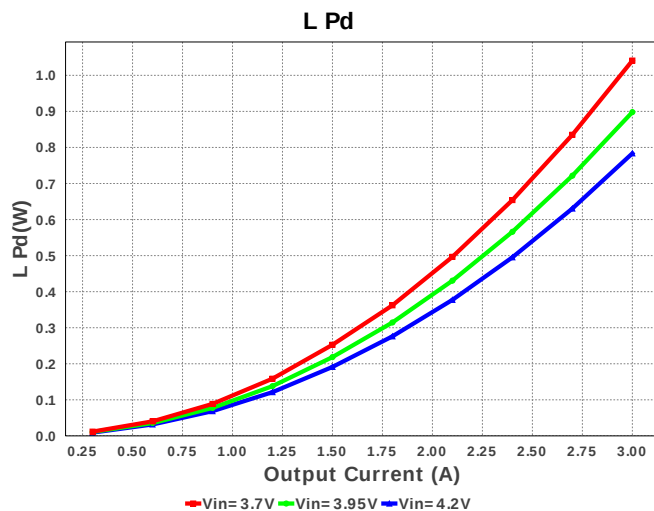
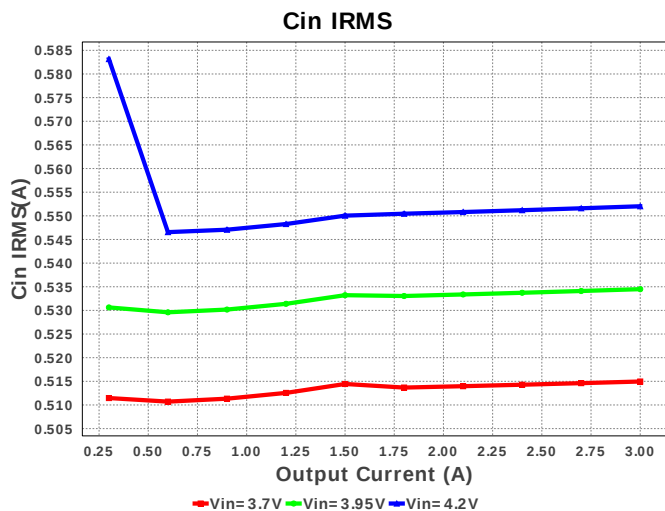


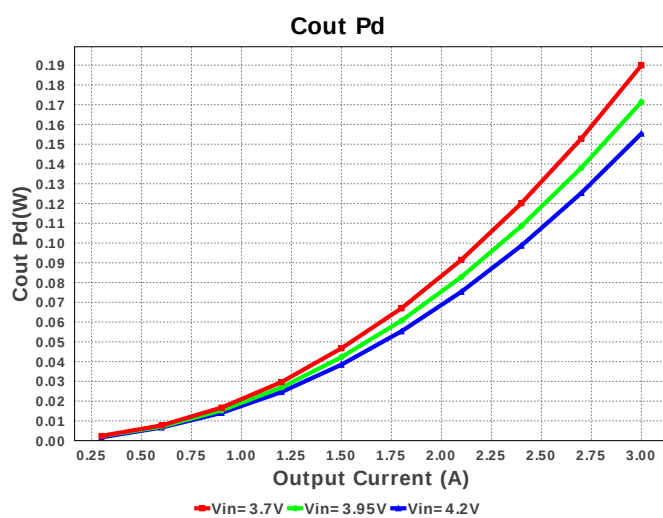
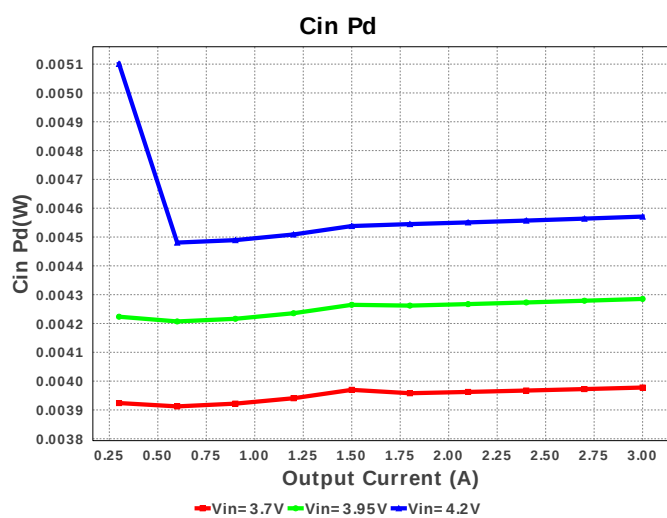
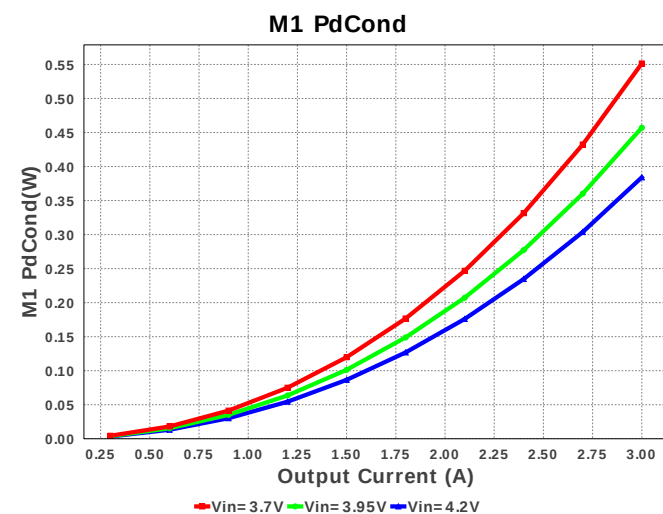
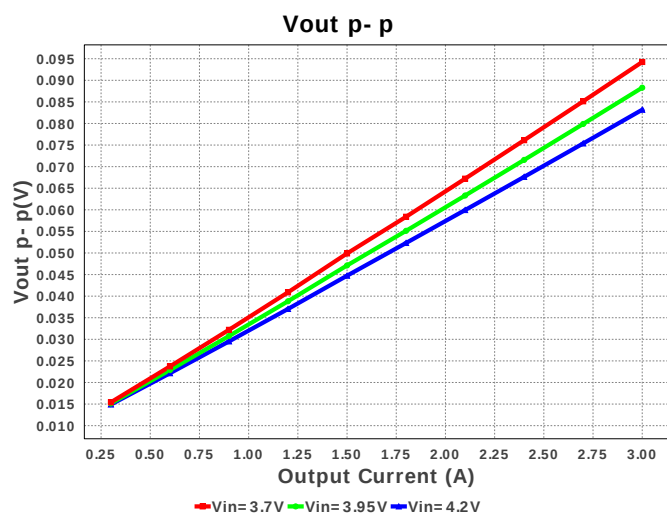
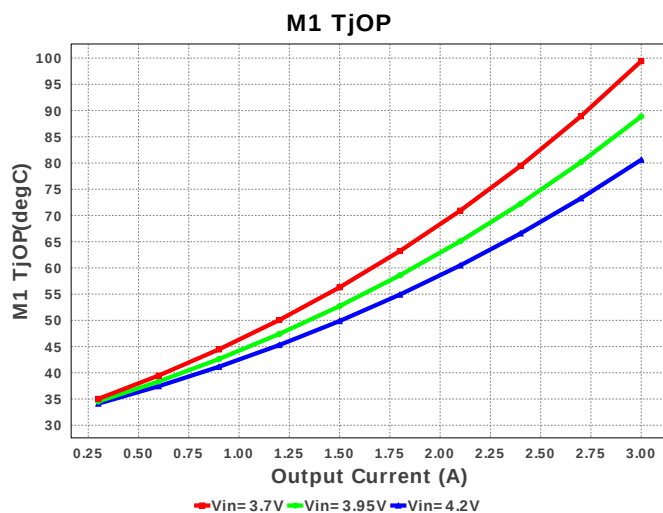
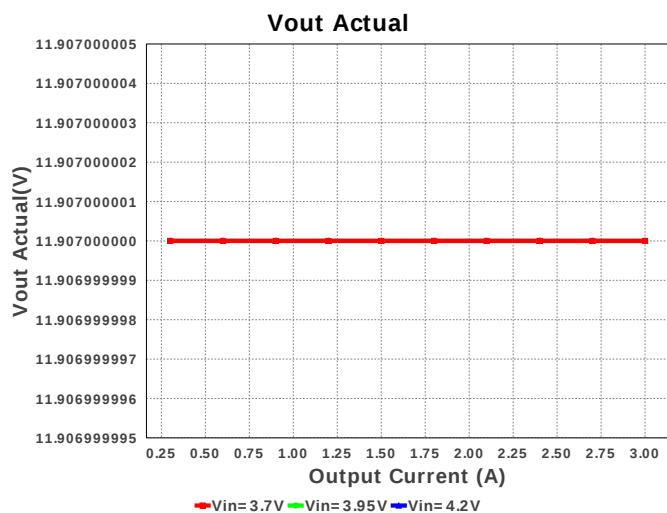


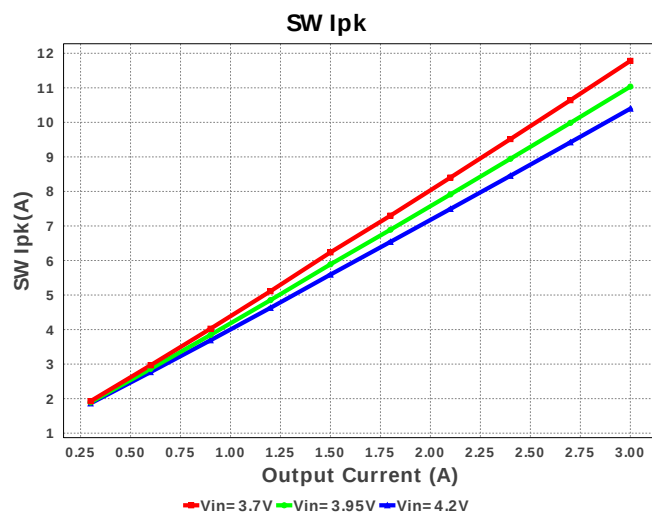
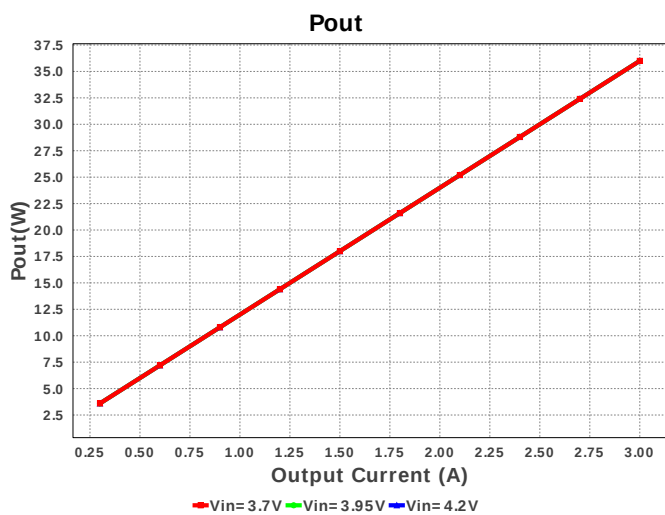
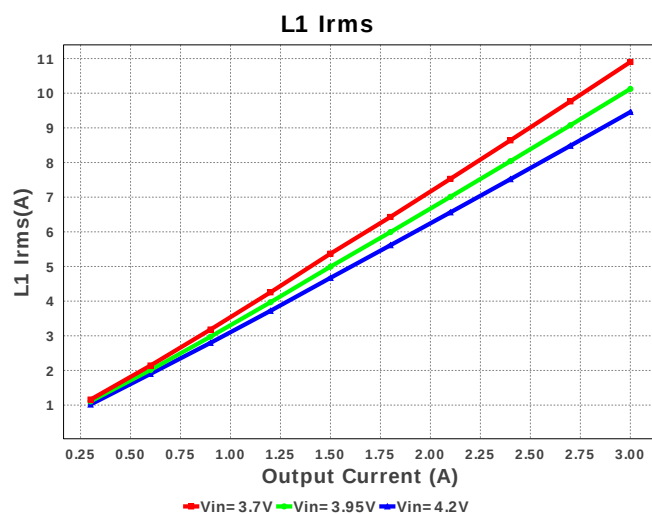
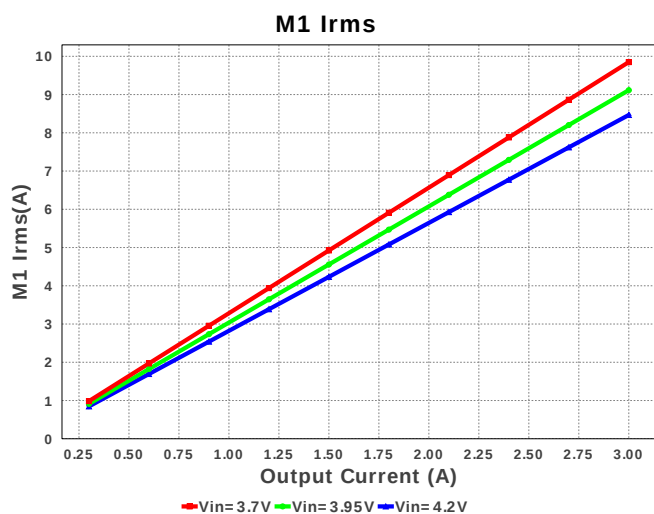
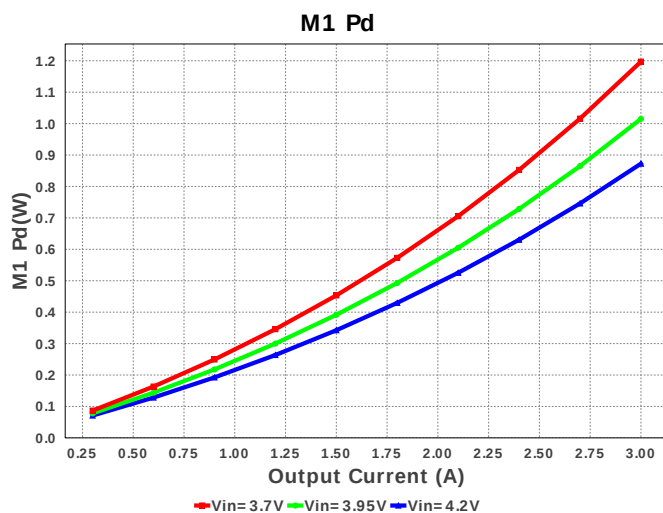
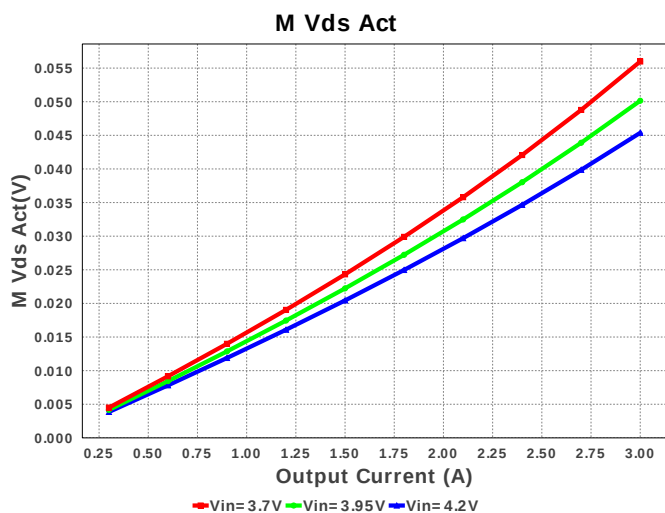
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Topology = Boost  
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BOM Count = 17  
Total Pd = 4.47W

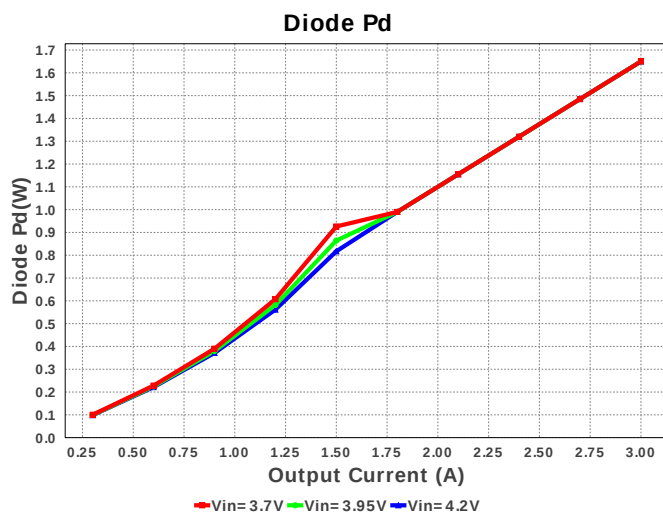
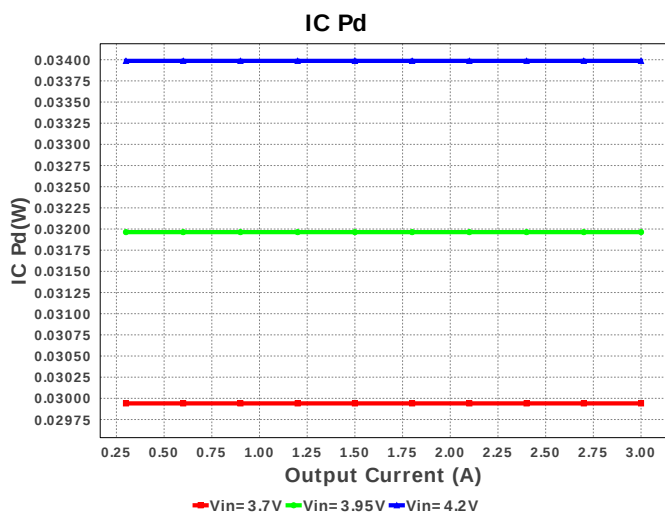
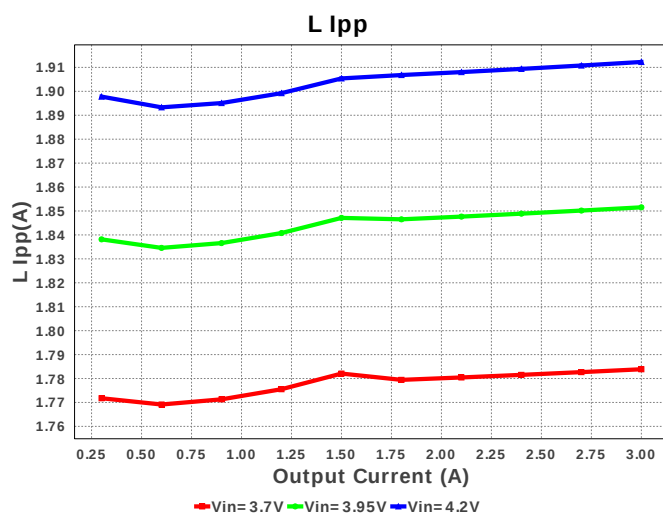
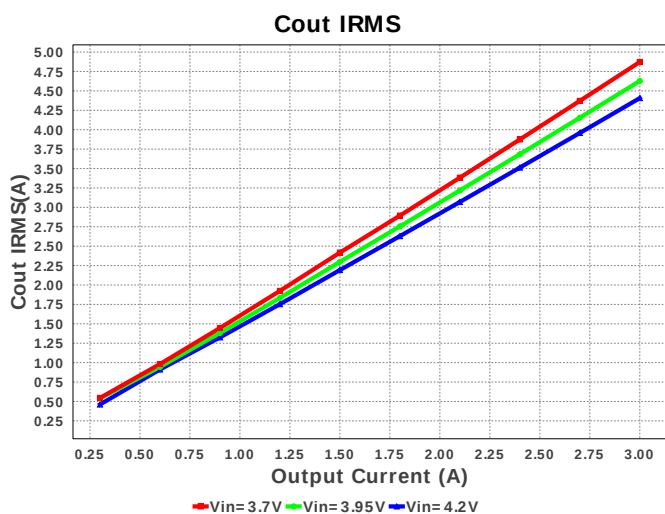
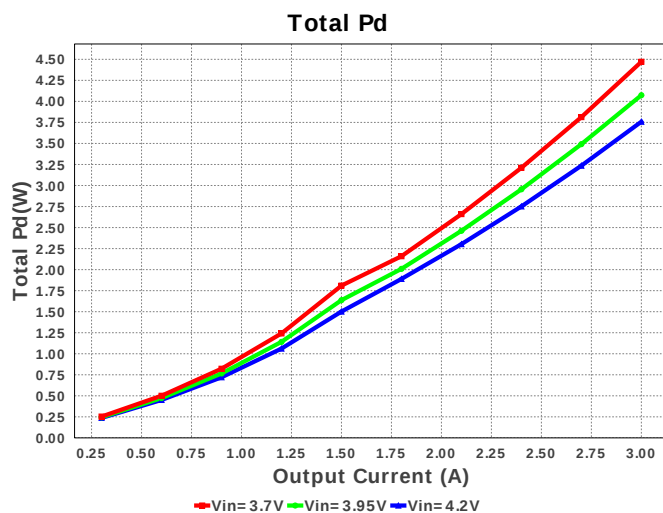
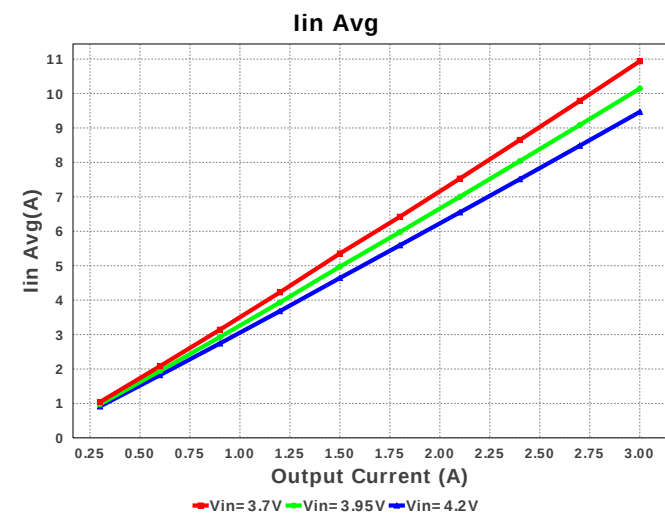
| #   | Name   | Manufacturer      | Part Number                          | Properties                                           | Qty | Price  | Footprint                                                                                                                 |
|-----|--------|-------------------|--------------------------------------|------------------------------------------------------|-----|--------|---------------------------------------------------------------------------------------------------------------------------|
| 8.  | L1     | Bourns            | SRP1250-2R7M                         | L= 2.7 $\mu$ H<br>DCR= 7.3 mOhm                      | 1   | \$0.64 | <br>SRP1250 253 mm <sup>2</sup>        |
| 9.  | M1     | Texas Instruments | CSD16323Q3                           | VdsMax= 25.0 V<br>IdsMax= 60.0 Amps                  | 1   | \$0.44 | <br>TRANS_NexFET_Q3 18 mm <sup>2</sup> |
| 10. | Rcomp  | Vishay-Dale       | CRCW04021K96FKED<br>Series= CRCW..e3 | Res= 1.96 kOhm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>             |
| 11. | Rfb1   | Vishay-Dale       | CRCW04021K00FKED<br>Series= CRCW..e3 | Res= 1000.0 Ohm<br>Power= 63.0 mW<br>Tolerance= 1.0% | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>             |
| 12. | Rfb2   | Vishay-Dale       | CRCW04028K45FKED<br>Series= CRCW..e3 | Res= 8.45 kOhm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>             |
| 13. | Rs1    | Vishay-Dale       | CRCW0402100RFKED<br>Series= CRCW..e3 | Res= 100.0 Ohm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>             |
| 14. | Rsense | Panasonic         | ERJ-M1WSF4M0U<br>Series= ERJ         | Res= 4.0 mOhm<br>Power= 1.0 W<br>Tolerance= 1.0%     | 1   | \$0.15 | <br>2512 43 mm <sup>2</sup>            |
| 15. | Rsync  | Vishay-Dale       | CRCW040226K1FKED<br>Series= CRCW..e3 | Res= 26.1 kOhm<br>Power= 63.0 mW<br>Tolerance= 1.0%  | 1   | \$0.01 | <br>0402 3 mm <sup>2</sup>             |
| 16. | U1     | Texas Instruments | LM3488QMMX/NOPB                      | Switcher                                             | 1   | \$0.96 | <br>MUA08A 24 mm <sup>2</sup>        |

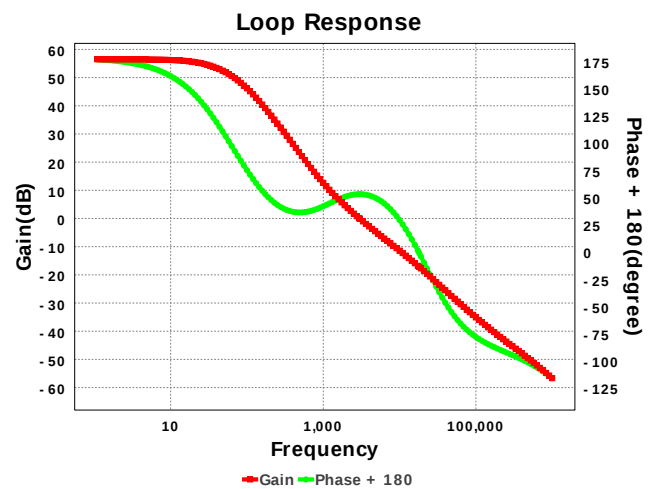
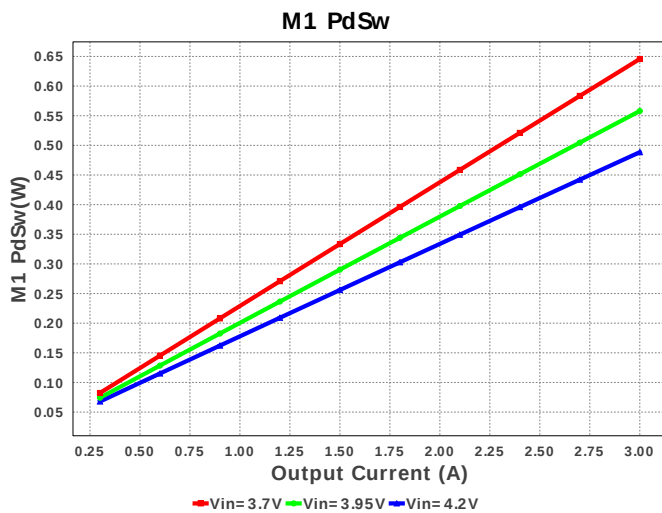
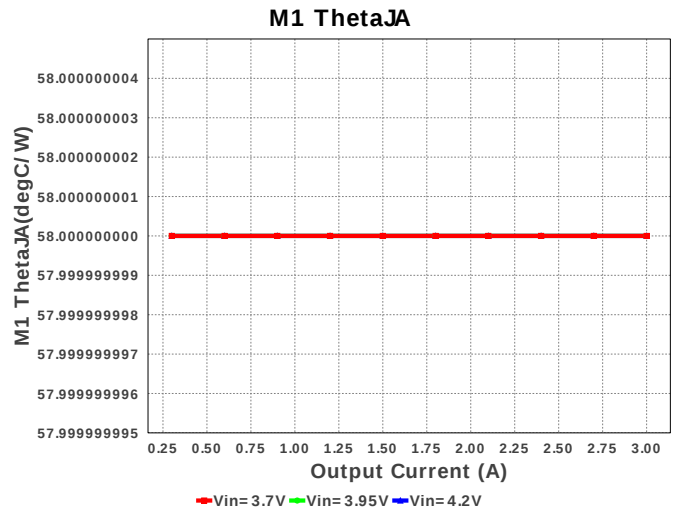
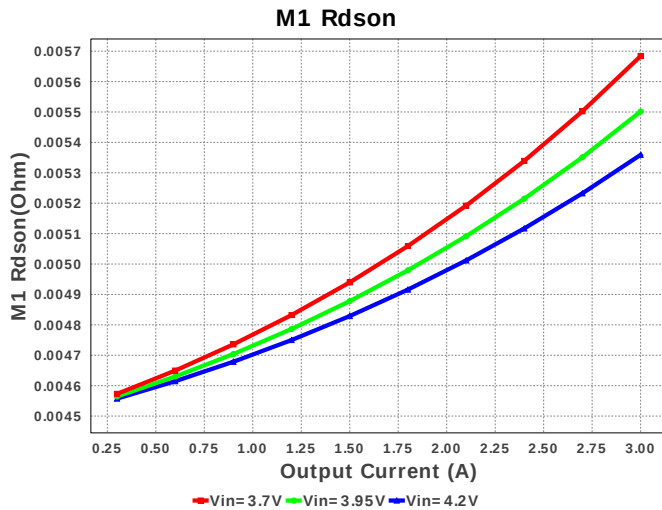












## Operating Values

| #   | Name          | Value                 | Category | Description                                                        |
|-----|---------------|-----------------------|----------|--------------------------------------------------------------------|
| 1.  | Cin IRMS      | 514.958 mA            | Current  | Input capacitor RMS ripple current                                 |
| 2.  | Cout IRMS     | 4.872 A               | Current  | Output capacitor RMS ripple current                                |
| 3.  | Iin Avg       | 10.938 A              | Current  | Average input current                                              |
| 4.  | L Ipp         | 1.784 A               | Current  | Peak-to-peak inductor ripple current                               |
| 5.  | L1 Irms       | 10.901 A              | Current  | Inductor ripple current                                            |
| 6.  | M1 Irms       | 9.849 A               | Current  | M1 MOSFET Irms                                                     |
| 7.  | SW Ipk        | 11.781 A              | Current  | Peak switch current                                                |
| 8.  | BOM Count     | 17                    | General  | Total Design BOM count                                             |
| 9.  | FootPrint     | 721.0 mm <sup>2</sup> | General  | Total Foot Print Area of BOM components                            |
| 10. | Frequency     | 550.0 kHz             | General  | Switching frequency                                                |
| 11. | IC Tolerance  | 15.3 mV               | General  | IC Feedback Tolerance                                              |
| 12. | M Vds Act     | 55.982 mV             | General  | M Vds                                                              |
| 13. | M1 Rdson      | 5.684 mOhm            | General  | Drain-Source On-resistance                                         |
| 14. | M1 ThetaJA    | 58.0 degC/W           | General  | MOSFET junction-to-ambient thermal resistance                      |
| 15. | Pout          | 36.0 W                | General  | Total output power                                                 |
| 16. | Total BOM     | \$3.87                | General  | Total BOM Cost                                                     |
| 17. | D1 Tj         | 112.5 degC            | Op_Point | D1 junction temperature                                            |
| 18. | Low Freq Gain | 55.244 dB             | Op_Point | Gain at 10Hz                                                       |
| 19. | Vout Actual   | 11.907 V              | Op_Point | Vout Actual calculated based on selected voltage divider resistors |
| 20. | Vout OP       | 12.0 V                | Op_Point | Operational Output Voltage                                         |
| 21. | Cross Freq    | 2.651 kHz             | Op_point | Bode plot crossover frequency                                      |
| 22. | Duty Cycle    | 72.449 %              | Op_point | Duty cycle                                                         |
| 23. | Efficiency    | 88.953 %              | Op_point | Steady state efficiency                                            |
| 24. | Gain Marg     | -16.23 dB             | Op_point | Bode Plot Gain Margin                                              |
| 25. | IC Tj         | 35.988 degC           | Op_point | IC junction temperature                                            |
| 26. | ICThetaJA     | 200.0 degC/W          | Op_point | IC junction-to-ambient thermal resistance                          |
| 27. | IOUT_OP       | 3.0 A                 | Op_point | Iout operating point                                               |
| 28. | M1 TJOP       | 99.432 degC           | Op_point | M1 MOSFET junction temperature                                     |
| 29. | Phase Marg    | 52.16 deg             | Op_point | Bode Plot Phase Margin                                             |
| 30. | VIN_OP        | 3.7 V                 | Op_point | Vin operating point                                                |
| 31. | Vout p-p      | 94.245 mV             | Op_point | Peak-to-peak output ripple voltage                                 |

| #   | Name           | Value      | Category | Description                                                                                |
|-----|----------------|------------|----------|--------------------------------------------------------------------------------------------|
| 32. | Cin Pd         | 3.978 mW   | Power    | Input capacitor power dissipation                                                          |
| 33. | Cout Pd        | 189.914 mW | Power    | Output capacitor power dissipation                                                         |
| 34. | Diode Pd       | 1.65 W     | Power    | Diode power dissipation                                                                    |
| 35. | IC Pd          | 29.94 mW   | Power    | IC power dissipation                                                                       |
| 36. | L Pd           | 1.041 W    | Power    | Inductor power dissipation                                                                 |
| 37. | M1 Pd          | 1.197 W    | Power    | M1 MOSFET total power dissipation                                                          |
| 38. | M1 PdCond      | 551.385 mW | Power    | M1 MOSFET conduction losses                                                                |
| 39. | M1 PdSw        | 645.715 mW | Power    | M1 MOSFET switching losses                                                                 |
| 40. | Rfb Pd         | 15.238 mW  | Power    | Rfb Power Dissipation                                                                      |
| 41. | Rsense Pd      | 421.129 mW | Power    | Rsense Power Dissipation                                                                   |
| 42. | Total Pd       | 4.471 W    | Power    | Total Power Dissipation                                                                    |
| 43. | Vout Tolerance | 3.043 %    |          | Vout Tolerance based on IC Tolerance (no load) and voltage divider resistors if applicable |

## Design Inputs

| #  | Name    | Value     | Description                        |
|----|---------|-----------|------------------------------------|
| 1. | Iout    | 3.0       | Maximum Output Current             |
| 2. | VinMax  | 4.2       | Maximum input voltage              |
| 3. | VinMin  | 3.7       | Minimum input voltage              |
| 4. | Vout    | 12.0      | Output Voltage                     |
| 5. | base_pn | LM3488-Q1 | Texas Instruments Base Part Number |
| 6. | source  | DC        | Input Source Type                  |
| 7. | ta      | 30.0      | Ambient temperature                |
| 8. | userfsw | 550.0 k   | Customer Selected Frequency        |

## Design Assistance

1. Feature Highlights: Automotive Qualified, 40V Wide Vin Low-Side N-Channel Controller for Switching Regulators
2. LM3488-Q1 Product Folder : <http://www.ti.com/product/lm3488q%2Dq1> : contains the data sheet and other resources.

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